

1N4728A through 1N4753A

Silicon Epitaxial Planar Zener Diodes for Stabilized Power Supply

HITACHI

ADE-208-136C (Z)

Rev.3
Sep. 2000

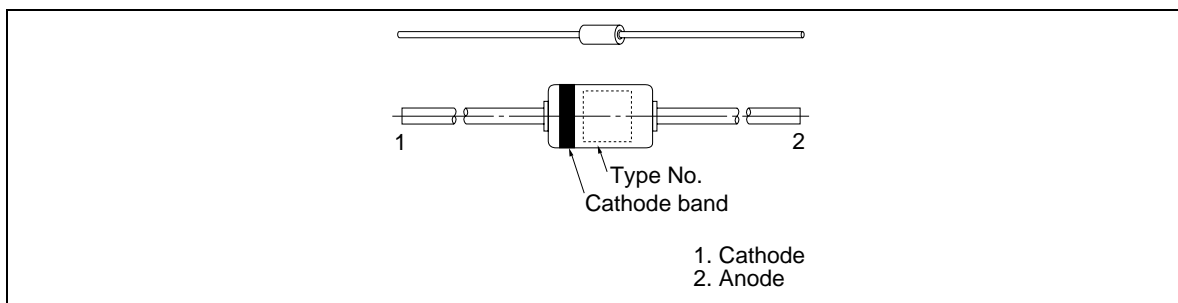
Features

- Glass package DO-41 structure ensures high reliability.
- Wide spectrum from 3.3V through 36V of zener voltage provide flexible application.

Ordering Information

| Type No. | Mark | Package Code |
|-------------------------|----------|--------------|
| 1N4728A through 1N4753A | Type No. | DO-41 |

Outline



Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

| Item | Symbol | Value | Unit |
|----------------------|-----------|-------------|------------------|
| Power dissipation | P_d *1 | 1.0 | W |
| Junction temperature | T_j | 200 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -65 to +200 | $^\circ\text{C}$ |

Note: 1. See Fig.3

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Electrical Characteristics

(T_a = 25°C)

| Type No. | V _Z (V) * ¹ | I _R (μA) | | Z _{ZT} (Ω) | | Z _{ZK} (Ω) | | I _{RSM} (mA)* ² | |
|----------|-----------------------------------|---------------------|----------------|---------------------|----------------|----------------------|----------------|-------------------------------------|----------------|
| | Max | Test Condition | Test Condition | Test Condition | Test Condition | Test Condition | Test Condition | Test Condition | Test Condition |
| | | I _Z (mA) | Max | V _R (V) | Max | I _{ZT} (mA) | Max | I _{ZK} (mA) | Max |
| 1N4728A | 3.3 ± 5 (%) | 76 | 100 | 1.0 | 10 | 76 | 400 | 1.0 | 1380 |
| 1N4729A | 3.6 ± 5 (%) | 69 | 100 | 1.0 | 10 | 69 | 400 | 1.0 | 1260 |
| 1N4730A | 3.9 ± 5 (%) | 64 | 50 | 1.0 | 9 | 64 | 400 | 1.0 | 1190 |
| 1N4731A | 4.3 ± 5 (%) | 58 | 10 | 1.0 | 9 | 58 | 400 | 1.0 | 1070 |
| 1N4732A | 4.7 ± 5 (%) | 53 | 10 | 1.0 | 8 | 53 | 500 | 1.0 | 970 |
| 1N4733A | 5.1 ± 5 (%) | 49 | 10 | 1.0 | 7 | 49 | 550 | 1.0 | 890 |
| 1N4734A | 5.6 ± 5 (%) | 45 | 10 | 2.0 | 5 | 45 | 600 | 1.0 | 810 |
| 1N4735A | 6.2 ± 5 (%) | 41 | 10 | 3.0 | 2 | 41 | 700 | 1.0 | 730 |
| 1N4736A | 6.8 ± 5 (%) | 37 | 10 | 4.0 | 3.5 | 37 | 700 | 1.0 | 660 |
| 1N4737A | 7.5 ± 5 (%) | 34 | 10 | 5.0 | 4 | 34 | 700 | 0.5 | 605 |
| 1N4738A | 8.2 ± 5 (%) | 31 | 10 | 6.0 | 4.5 | 31 | 700 | 0.5 | 550 |
| 1N4739A | 9.1 ± 5 (%) | 28 | 10 | 7.0 | 5 | 28 | 700 | 0.5 | 500 |
| 1N4740A | 10 ± 5 (%) | 25 | 10 | 7.6 | 7 | 25 | 700 | 0.25 | 454 |
| 1N4741A | 11 ± 5 (%) | 23 | 5 | 8.4 | 8 | 23 | 700 | 0.25 | 414 |
| 1N4742A | 12 ± 5 (%) | 21 | 5 | 9.1 | 9 | 21 | 700 | 0.25 | 380 |
| 1N4743A | 13 ± 5 (%) | 19 | 5 | 9.9 | 10 | 19 | 700 | 0.25 | 344 |
| 1N4744A | 15 ± 5 (%) | 17 | 5 | 11.4 | 14 | 17 | 700 | 0.25 | 304 |
| 1N4745A | 16 ± 5 (%) | 15.5 | 5 | 12.2 | 16 | 15.5 | 750 | 0.25 | 285 |
| 1N4746A | 18 ± 5 (%) | 14.0 | 5 | 13.7 | 20 | 14.0 | 750 | 0.25 | 250 |
| 1N4747A | 20 ± 5 (%) | 12.5 | 5 | 15.2 | 22 | 12.5 | 750 | 0.25 | 225 |
| 1N4748A | 22 ± 5 (%) | 11.5 | 5 | 16.7 | 23 | 11.5 | 750 | 0.25 | 205 |
| 1N4749A | 24 ± 5 (%) | 10.5 | 5 | 18.2 | 25 | 10.5 | 750 | 0.25 | 190 |
| 1N4750A | 27 ± 5 (%) | 9.5 | 5 | 20.6 | 35 | 9.5 | 750 | 0.25 | 170 |
| 1N4751A | 30 ± 5 (%) | 8.5 | 5 | 22.8 | 40 | 8.5 | 1000 | 0.25 | 150 |
| 1N4752A | 33 ± 5 (%) | 7.5 | 5 | 25.1 | 45 | 7.5 | 1000 | 0.25 | 135 |
| 1N4753A | 36 ± 5 (%) | 7.0 | 5 | 27.4 | 50 | 7.0 | 1000 | 0.25 | 125 |

Notes: 1. Tested with DC

2. t = 1/120 sec reverse direction 1pulse

Main Characteristic

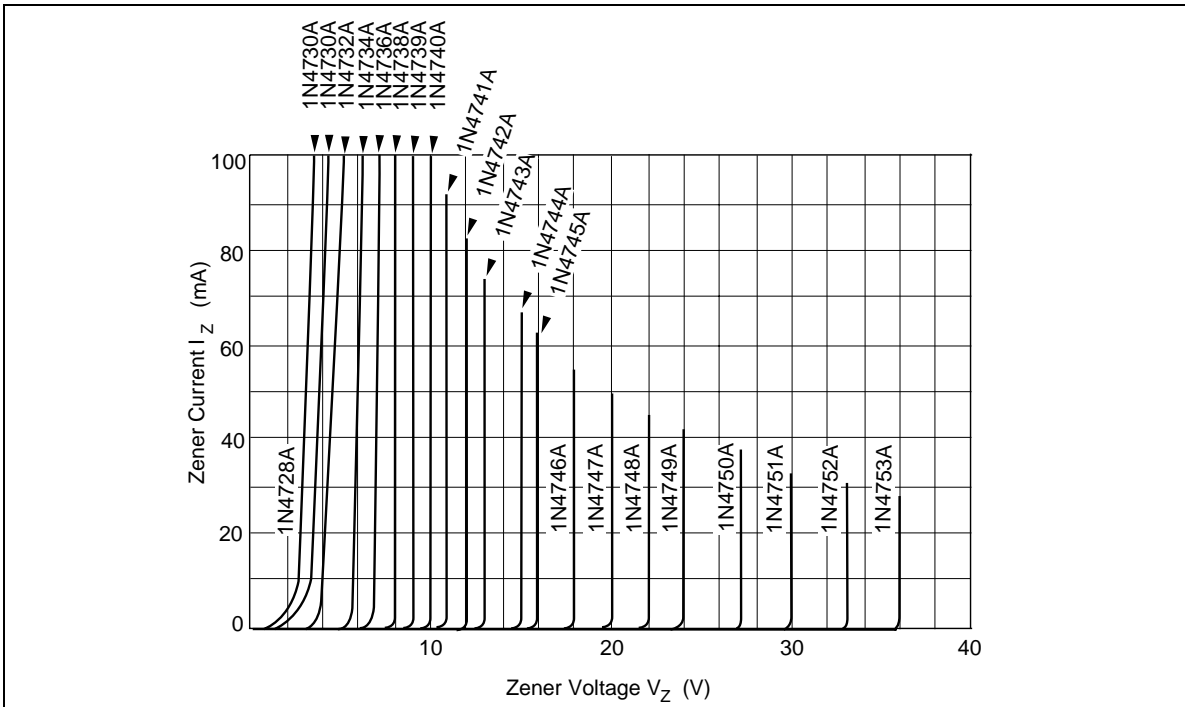


Fig.1 Zener current Vs. Zener voltage

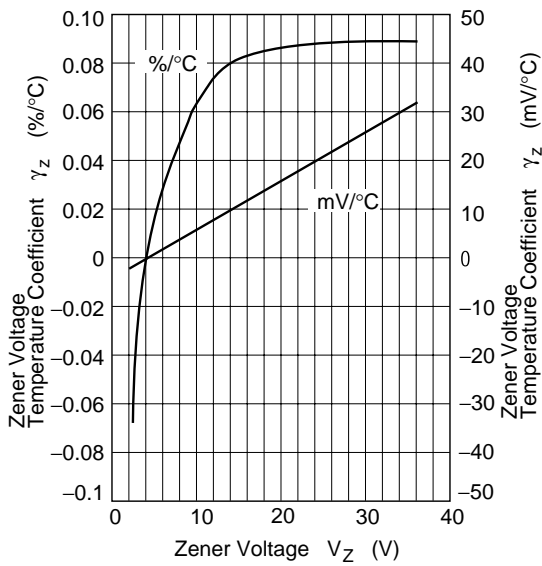


Fig.2 Temperature Coefficient Vs. Zener voltage

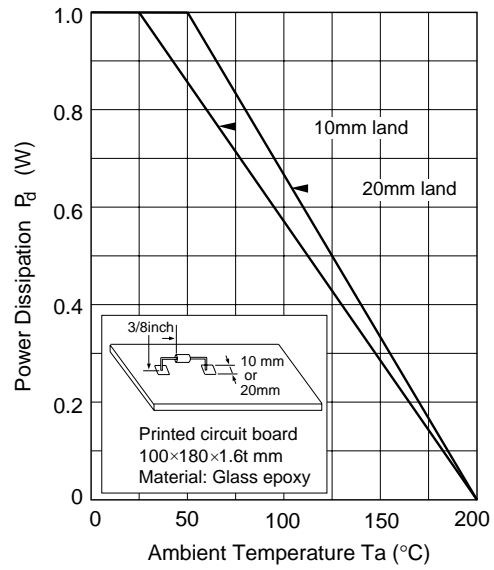


Fig.3 Power Dissipation Vs. Ambient Temperature

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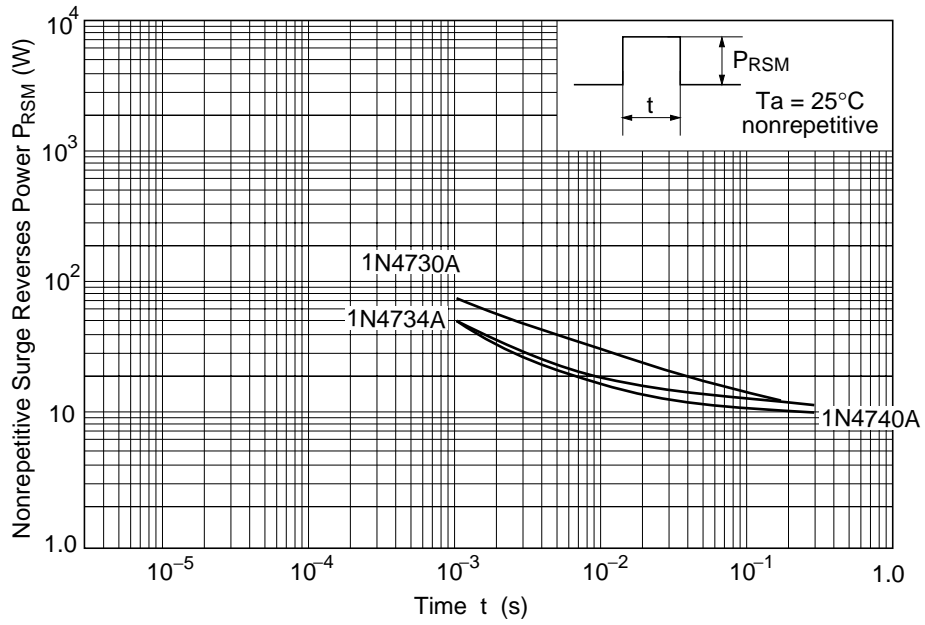


Fig.4 Surge Reverse Power Ratings

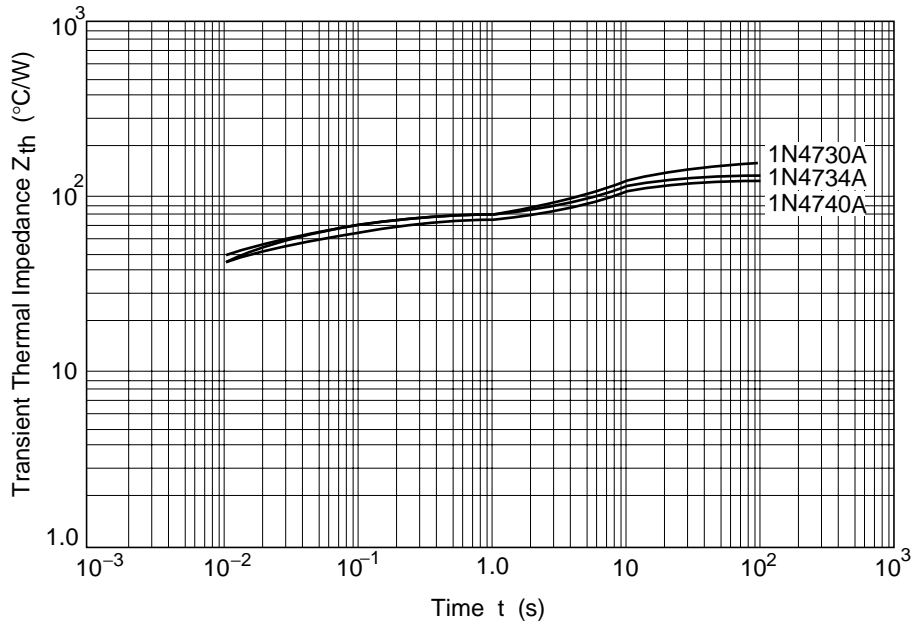
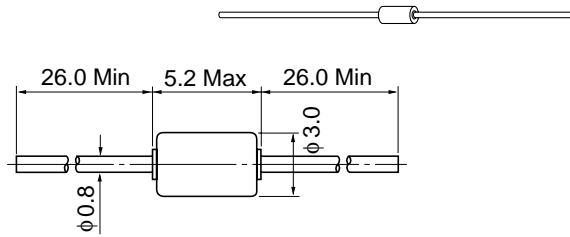


Fig.5 Transient Thermal Impedance

1N4728A through 1N4753A

Package Dimensions

Unit: mm



| | |
|------------------------|----------|
| Hitachi Code | DO-41 |
| JEDEC | Conforms |
| EIAJ | Conforms |
| Mass (reference value) | 0.38 g |

1N4728A through 1N4753A

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